Rare earth engineering in RMn\textsubscript{6}Sn\textsubscript{6} topological kagome magnets

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Exploration of the topological quantum materials with electron correlation is at the frontier of physics, as the strong interaction may give rise to new topological phases and transitions. Here we report that a family of kagome magnets RMn\textsubscript{6}Sn\textsubscript{6} manifest the quantum transport properties analoqous to those in the quantum-limit Chern magnet TbMn\textsubscript{6}Sn\textsubscript{6}. The topological transport in the family, including quantum oscillations with nontrivial Berry phase and large anomalous Hall effect arising from Berry curvature field, points to the existence of massive Dirac fermions. Our observation demonstrates a close relationship between rare-earth magnetism and topological electron structure, indicating the rare-earth elements can effectively engineer the Chern quantum phase in kagome magnets.

The interplay between lattice geometry and electron correlation can create new states of quantum matter, with recent examples including twisted bilayer graphene,\textsuperscript{6,7} Kitaev quantum spin liquid,\textsuperscript{8,9} and kagome Chern magnet.\textsuperscript{10,11} A kagome lattice, consisting of two-dimensional corner-sharing triangles, naturally hosts both relativistic and dispersionless electrons,\textsuperscript{12,13} which are the origins of its nontrivial band topology. With the inclusion of magnetism and spin-orbit coupling (SOC), kagome electrons can realize strongly interacting topological phases.\textsuperscript{10,12,14} Recent study\textsuperscript{11} has found a near-ideal quantum limit Chern magnet TbMn\textsubscript{6}Sn\textsubscript{6}, which hosts defect-free Mn kagome lattice. However the topological nature of other family remains largely unexplored. The RMn\textsubscript{6}Sn\textsubscript{6} system features a pristine Mn\textsubscript{4} kagome lattice (Fig. 1(a)) in a layered structure.\textsuperscript{17} They all exhibit magnetic ordering of Mn moments at room temperature while different R gives rise to various magnetic structures.\textsuperscript{10–18} Of particular, TbMn\textsubscript{6}Sn\textsubscript{6} manifests a ferrimagnetic (FIM) structure in which Tb sublattice is anti-parallel with out-of-plane ferromagnetically (FM) ordered Mn lattice. This FIM structure has been proven to effectively sustain the spinless Haldane model generating Chern gapped massive Dirac fermions (MDFs), as illustrated in Fig. 1(b)\textsuperscript{4,10,11}. In this work we investigate the topological properties of the Mn kagome lattices in a series of RMn\textsubscript{6}Sn\textsubscript{6} (R = Gd - Tm, Lu). Their magnetic ground states are classified as FIM when R = Gd to Ho, and antiferromagnetic (AFM) when R is Er, Tm and Lu (Fig. 1(c)). We found in general MDFs exist in the FM ordered kagome lattice of RMn\textsubscript{6}Sn\textsubscript{6} but is absent in the AFM states. The Chern gap (\(\Delta\)) and the Dirac cone energy (\(E_D\)) follow a decreasing trend from R = Gd to Er. As we argue below, this R engineering on the topological electron structure is intimately related to the coupling between 4f local moment and Mn 3d moment. In particular, \(\Delta\) is proportional to the de Gennes factor (\(dG\)) of 4f moments while \(E_D\) is proportional to \(\sqrt{dG}\). The interplay of the magnetic order and topological structure remains a fertile ground in the systems with strong correlation. Our finding demonstrates that a local-moment-bearing R can serve as a knob for tuning the topological properties in quantum magnets.

RMn\textsubscript{6}Sn\textsubscript{6} single crystals were synthesized via a flux method.\textsuperscript{18,21} All these metals are magnetically ordered above room temperature (Fig. 1(c)) while the magnetic R sublattice tends to develop an anti-parallel configuration with respect to Mn if the Mn lattice is FM ordered.\textsuperscript{17,18} The magnetic anisotropy varies from easy-ab-plane for R = Gd, to easy-c-axis for R =...
frequency, $\beta$ and axis in Fig. 1(g) all give $\gamma$ oscillatory frequency (Fig. 1(f)). We obtain the Berry quantum oscillations (SdH QOs) with a close and small $m^*$, which constrain our analysis along this direction. Firstly, the Fermi surface of the pocket is detected to be 2D in angular dependent measurements [11]. Secondly, the QOs are intimately related with the FM order in the Mn kagome lattice (R = Gd - Ho and Er) while no QO is expected as their lattice parameters differ less than 0.4 %. A series of experiments including the scanning tunneling microscopy (STM) and angle-resolved photoemission spectroscopy (ARPES) [11] connect the SdH QOs with the MDF in TbMn$_6$Sn$_6$. This connection is also experimentally established in GdMn$_6$Sn$_6$ (ARPES data in Section II of the Supplemental Material [28]). We conclude that the Chern gapped MDF is generally hosted in FM Mn kagome lattice of RMn$_6$Sn$_6$ (R = Gd to Er). We highlight two key features of these QOs that constrain our analysis along this direction. Firstly, the Fermi surface of the pocket is detected to be 2D in angular dependent measurements [11]. Secondly, the QOs are intimately related with the FM order in the Mn kagome lattice (R = Gd - Ho and Er) while no QO is observed in AFM Tm, Lu or Y members.

To further understand the interplay between the magnetic structure and topological property, we systematically study the magnetization and anomalous Hall effect as shown in Fig. 2. We take DyMn$_6$Sn$_6$ as an example, which has a conical magnetic structure below room temperature. The $M(H)$ shows a hard-magnet-like profile with sharp, considerable hysteresis loops below 100 K (Fig. 2(c)). With increasing external field, there exists a continuous rotation of the magnetic moments towards $c$-axis. The Hall resistivity ($\rho_{yx}$) resembles the profile of its $M(H)$ completely. We separate the anomalous contribution (Section III of the Supplemental Material [28]) using the empirical relation [37],

$$\rho_{yx} = \rho_{OH}(B) + \rho_{AH}(M) = R_0 B + R_S 4\pi M$$

where $\rho_{OH}$ and $\rho_{AH}$ represent ordinary and anomalous Hall resistivity, $R_0$ and $R_S$ are ordinary and anomalous Hall coefficients, respectively. Similar phenomena hold for Gd, Tb and Ho members. ErMn$_6$Sn$_6$ lies between FIM and AFM states and a small field triggers a metamagnetic transition which represents as a sharp jump on the $M(H)$ curves below 100 K (Fig. 2(e)). Its $\rho_{yx}$ curves also follow the $M(H)$ curves (Fig. 5(e)) and

<table>
<thead>
<tr>
<th>R</th>
<th>$\sigma_{int}^\gamma(e^2/h)$</th>
<th>F(T)</th>
<th>$m^*(m_0)$</th>
<th>$v_F(10^5 m/s)$</th>
<th>$k_F(\AA^{-1})$</th>
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<tr>
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<td>0.11</td>
<td>5.4</td>
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<td>96</td>
<td>0.14</td>
<td>4.5</td>
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<tr>
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<td>71</td>
<td>0.10</td>
<td>5.4</td>
<td>0.046</td>
</tr>
<tr>
<td>Ho</td>
<td>0.09</td>
<td>55</td>
<td>0.12</td>
<td>4.0</td>
<td>0.041</td>
</tr>
<tr>
<td>Er</td>
<td>0.04</td>
<td>35</td>
<td>0.11</td>
<td>3.4</td>
<td>0.033</td>
</tr>
</tbody>
</table>

TABLE I. MDFs in RMn$_6$Sn$_6$. $\sigma_{int}^\gamma$: the intrinsic anomalous Hall conductivity. $F$ and $m^*$: frequency and cyclotron mass of SdH QOs. $v_F$ and $k_F$: Fermi velocity and wave vector.

FIG. 1. Crystal structure, physical property and topological electrons in RMn$_6$Sn$_6$. (a) Mn kagome layers and R sublattices in RMn$_6$Sn$_6$. (b) Illustration of MDF with a Chern gap in the magnetic kagome lattice. (c) Magnetic structures in zero field. Blue and green arrows represent the direction of Mn and R moments, respectively. (d) $\rho(T)$ curves for single crystals. Inset: Crystallographic orientations. (e) M(T) for $\mu_0 H = 1T$. (f) SdH QOs at 2 K. (g) Landau fan diagram. Peak positions in (f) are assigned with half-integral Landau indexes [11]. Inset: Zoom-in near $N = 0$.

The above analyses demonstrate that the electronic structures of RMn$_6$Sn$_6$ resemble each other, which is expectable as their lattice parameters differ less than 0.4 %. A series of experiments including the scanning tunneling microscopy (STM) and angle-resolved photoemission spectroscopy (ARPES) [11] connect the SdH QOs with the MDF in TbMn$_6$Sn$_6$. This connection is also experimentally established in GdMn$_6$Sn$_6$ (ARPES data in Section II of the Supplemental Material [28]). We conclude that the Chern gapped MDF is generally hosted in FM Mn kagome lattice of RMn$_6$Sn$_6$ (R = Gd to Er). We highlight two key features of these QOs that constrain our analysis along this direction. Firstly, the Fermi surface of the pocket is detected to be 2D in angular dependent measurements [11]. Secondly, the QOs are intimately related with the FM order in the Mn kagome lattice (R = Gd - Ho and Er) while no QO is observed in AFM Tm, Lu or Y members.
we can distinguish $\rho_{AH}$ as the step on the transition. For Tm and Lu, the stable AFM structure \[17\,18\] defies explicit zero-field anomalous effect in their $\rho_{xx}$, similar as the observation for YMn$_6$Sn$_6$ \[23\,24\]. Interestingly, $\rho_{AH}$ in TmMn$_6$Sn$_6$ deviates from the linear $M(H)$ above 100 K (Fig. 2(f)), which might arise from a topological Hall effect (THE) and deserves attention in future.

The scaling relation between the anomalous Hall conductivity (AHC) $\sigma_{AH} \simeq \rho_{AH}/\rho_{xx}^2$ and $\sigma_{xx}$ is shown in Fig. 2(h). Previous studies have identified three distinct regimes which are delimited by $\sigma_{xx}$ and characterized by the dependence of $\sigma_{AH}$ and $\sigma_{xx}$ \[32\,40\]. For RMn$_6$Sn$_6$, $\sigma_{xx}$ ranges from $3 \times 10^3$ to $5 \times 10^3$ $\Omega^{-1}$ cm$^{-1}$, approximately lying within the good-metal regime. Their $\sigma_{AH}$, of the order 100 $\Omega^{-1}$ cm$^{-1}$, keeps nearly invariant in this regime, suggesting dominant intrinsic contributions. By fitting the scaling law (Section V of the Supplemental Material \[28\]), we extract the intrinsic Hall conductivity $\sigma_{int}$ to be around $0.14 - 0.04e^2/h$ per kagome layer for R = Gd to Er, as summarized in Table I.

A high-temperature quantum anomalous Hall effect with a quantized Hall value $e^2/h$ is theoretically supported by a Chern insulating gap of the MDF \[10\]. In RMn$_6$Sn$_6$, the Chern gap is near the Fermi level and therefore its Berry curvature field should induce a large intrinsic AHC. The AHC for MDF is estimated as \[41\]

$$\sigma_{int} = \frac{e^2}{h} \frac{\Delta}{\sqrt{\Delta^2 + 4\hbar^2k_F^2v_F^2}} = \frac{e^2}{2h} \frac{\Delta}{E_D} \quad (2)$$

As $\Delta$ and $E_D$ in TbMn$_6$Sn$_6$ have been completed depicted by STM, the agreement between theoretically inferred AHC and our transport data indicates that the MDF dominates the Berry curvature field \[11\]. Assuming $\sigma_{int}$ is stemming from the MDF in the kagome lattice in other RMn$_6$Sn$_6$ as well, we evaluate the effective $\Delta$ and $E_D$. Interestingly, both parameters gradually decrease when R changes from Gd to Er (Fig. 3).

The analysis highlights the possibility of Chern phase engineering in RMn$_6$Sn$_6$ by changing the R atoms. Regulating the Chern gap has been less accomplished in experiments and one example is Fe$_3$Sn$_2$ whose gap can be modulated by applying an external magnetic.
field \[42, 43\]. Here we observe a unique, intrinsic R engineering of topological electrons in a kagome magnet, and its mechanism needs further elaboration. The chemical pressure does not likely play a role because the lattice parameter changes little in the series. On the other hand, the total SOC strength should increase slightly with the atomic number from R = Gd to Er, which is opposite to the trend of gap closing. Below we discuss one possible mechanism.

When we plot \(\Delta\) and \(E_D\) against \(dG\) = \((g_f - 1)^2J(J + 1)\), where \(g_f\) is the Landé factor and \(J\) is the total angular momentum of the \(R^{3+}\) ion Hund’s rule ground state, we find they apparently follow a linear and square root relation, respectively, as shown in Fig. 3. We propose that the coupling between 4\(f\) moments and 3\(d\) electrons of Mn plays a crucial role in this engineering. If we include the hopping between Mn and R (Fig. 3(a)), it will introduce an additional diagonal component in total Hamiltonian, which is proportional to \(-J_H m\), where \(J_H\) is the Hund’s coupling, \(m\) equals \((g_f - 1)\sqrt{J(J + 1)} = \sqrt{dG}\) is the effective moment of R ions in mean-field approximation [44]. Considering this first-order hopping process we naturally conclude that the chemical potential of the MDF should shift linearly with \(\sqrt{dG}\). The first-order process should not contribute to the gap opening on \(K(K’)\) valley because of the symmetry of a kagome lattice. To elucidate the gap opening, higher order process (for instance, the two-electron hopping in Fig. 4(b)) has to be considered (Section VII of the Supplemental Material [28]). The fourth order perturbation will open a gap proportional to \(\sim J_H^2 m^2\), namely \(\Delta \propto dG\), just as what we have observed in experiment.

The magnetic exchange coupling between 3\(d\) and 4\(f\) electrons plays an important role in the magnetic properties of RMn\(_6\)Sn\(_6\) as well [13–18]. Phenomenologically, this coupling is weakened when R changes from Gd to Tm. ErMn\(_6\)Sn\(_6\) has a critically weak coupling which makes it lie at the border between FIM and AFM ground states and we notice it also has the smallest \(\Delta\) and \(E_D\). This interesting observation supports the critical role of magnetic coupling in the MDF structure. On the other hand, the THE and electronic structure in YMn\(_6\)Sn\(_6\) which has no 4\(f\) moments, deserve further elaborations [23–25]. Our work highlights the material system which not only largely extends the family of quantum kagome magnets, but also intrinsically contains a quantum knob for Chern phase engineering. The quantum tuning of the topological band structures via magnetic coupling may serve as a pathway to engineer the topological phases in correlated systems.

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[28] See Supplemental Material at [URL] for experimental and theoretical details as well as additional figures and discussions, which includes Refs. [29-36].